

3.3V LVDS High-Speed Differential Line Driver and Receiver

Features

- Signaling Rates >660 Mbps (330 MHz)
- Single 3.3V Power Supply Design
- Driver:
 - $\pm 350\text{mV}$ Differential Swing into a 100-ohm load
 - Propagation Delay of 1.5ns Typ.
 - Low Voltage TTL (LVTTL) Inputs are 5V Tolerant
- Receiver:
 - Accepts $\pm 50\text{mV}$ (min.) Differential Swing with up to 2.0V ground potential difference
 - Propagation Delay of 3.3ns Typ.
 - Low Voltage TTL (LVTTL) Outputs
 - Open, Short, and Terminated Fail Safe
- Industrial Temperature Operating Range: -40°C to 85°C
- Meets or Exceeds IEEE 1596.3 SCI Standard
- Meets or Exceeds ANSI/TIA/EIA-644 LVDS Standard
- Bus terminal ESD = 2KV HBM
- Packaging (Pb-free & Green available):
 - 8-pin SOIC or MSOP

Description

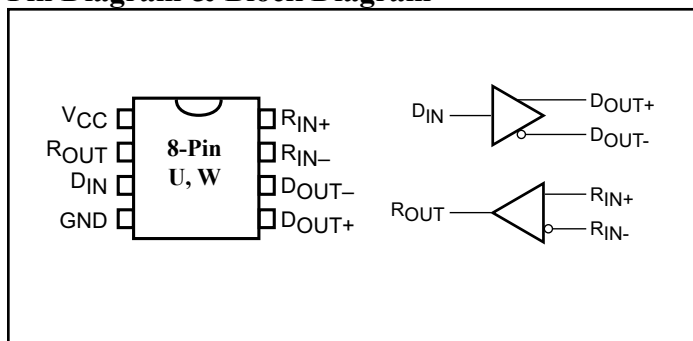
The PI90LV179 is a differential line driver and receiver (transceiver) that is compliant with the IEEE 1596.3 SCI and ANSI/TIA/EIA-644 LVDS standards. This device uses low-voltage differential signaling (LVDS) to achieve data rates in excess of 660 Mbps while being less susceptible to noise than single-ended transmission.

The driver translates a low-voltage TTL/CMOS input into a low-voltage (350mV typical) differential output signal. The receiver translates a differential 350mV input signal to a 3V CMOS output level.

Applications

Applications include point-to-point and multidrop baseband data transmission over a controlled impedance media of approximately 100 ohms. These include intra-system connections via printed circuit board traces or cables, hubs and routers for data communications; PBXs, switches, repeaters and base stations for telecommunications and other applications such as digital cameras, printers and copiers.

Pin Diagram & Block Diagram



Function Tables

PI90LV179 Receiver

| Inputs | Output |
|--------------------------------|--------|
| $V_{ID} = V_{RIN+} - V_{RIN-}$ | H |
| $V_{ID} \geq 50mV$ | H |
| $-50mV < V_{ID} < 50mV$ | ? |
| $V_{ID} \leq -50mV$ | L |
| open | H |

PI90LV179 Driver

| Input | Output | |
|----------|------------|------------|
| D_{IN} | D_{OUT+} | D_{OUT-} |
| L | L | H |
| H | H | L |
| open | L | H |

Notes:

H = High Level, L = Low Level, ? = Indeterminate,
Z = High-Impedance, X = Don't Care

Pin Descriptions

| Pin Name | Description |
|------------|---------------------------------------|
| D_{IN} | TTL/CMOS driver input pin |
| D_{OUT+} | Non-inverting driver output pin |
| D_{OUT-} | Inverting driver output pin |
| R_{OUT} | TTL/CMOS receiver output pin |
| R_{IN+} | Non-inverting receiver input pin |
| R_{IN-} | Inverting receiver input pin |
| GND | Ground pin |
| V_{CC} | Positive power supply pin, +3.3V ±10% |

Absolute Maximum Ratings

| | |
|--|------------------------------|
| Supply Voltage (V_{CC})..... | -0.5V to +4.0V |
| Driver | |
| Input Voltage (D_{IN}) | -0.3V to ($V_{CC} + 0.3V$) |
| Output Voltage (D_{OUT+}, D_{OUT-})..... | -0.3V to +3.9V |
| Short Circuit Duration (D_{OUT+}, D_{OUT-})..... | Continuous |
| Receiver | |
| Input Voltage (R_{IN+}, R_{IN-}) | -0.3V to +3.9V |
| Output Voltage (R_{OUT}) | -0.3V to ($V_{CC} + 0.3V$) |
| Storage Temperature Range | -65°C to +150°C |
| ESD Rating..... | 2kV HBM |

Note: Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

| | Min. | Typ. | Max. | Units |
|--|--------------|------|----------------------|-------|
| Supply Voltage (V_{CC}) | 3 | 3.3 | 3.6 | V |
| High Level Input Voltage, V_{IH} | 2 | | | |
| Low Level Input Voltage, V_{IL} | | | 0.8 | |
| Magnitude of Differential Input Voltage V_{ID} | 0.1 | | 0.6 | |
| Common-mode Input Voltage, V_{IC} (Fig 5) | $ V_{ID} /2$ | | 2.4 $- V_{ID} /2$ | |
| | | | $V_{CC} - 0.8$ | |
| Operating Free Air Temperature T_A | -40 | | 85 | °C |

Electrical Characteristics (Over recommended operating conditions unless otherwise noted).

| Parameter | Test Condition | Min. | Typ. ⁽¹⁾ | Max. | Units |
|-------------------------------|---|------|---------------------|------|-------|
| $I_{CC}^{(2)}$ Supply Current | No receiver load, Driver $R_L = 100$ ohms | | 8.0 | 10.8 | mA |

Notes:

- All typical values are at 25°C with a 3.3V supply
- I_{CC} measured with all TTL input. $V_{IN} = V_{CC}$ or GND.

Electrical Characteristics (Over recommended operating conditions unless otherwise noted).

| Parameter | | Test Conditions | Min. | Typ. | Max. | Units |
|---------------------|--|---|-------|------|-------|-------|
| $ V_{OD} $ | Differential output voltage magnitude | $R_L = 100$ ohms See Figures 1 and 2 | 247 | 390 | 470 | mV |
| $\Delta V_{OD} $ | Change in differential output voltage magnitude between logic states | | -50 | | 50 | |
| $V_{OC(SS)}$ | Steady-state common-mode output voltage | See Figure 3 | 1.125 | 1.25 | 1.375 | V |
| $\Delta V_{OC(SS)}$ | Change in steady-state common-mode output voltage between logic states | | -50 | | 50 | mV |
| $V_{OC(PP)}$ | Peak-to-peak common-mode output voltage | | | 50 | 150 | |

| Parameter | | Test Conditions | Min. | Typ. | Max. | Units | |
|--------------|------------------------------|-----------------|---------------------------|------|------|---------|---------|
| I_{IH} | High-level input current | D_{IN} | $V_{IH} = 5V$ | | 2 | 20 | μA |
| I_{IL} | Low-level input current | D_{IN} | $V_{IL} = 0.8V$ | | 2 | 10 | |
| I_{OS} | Short-circuit output current | | V_{OY} or $V_{OZ} = 0V$ | | -6 | -9 | mA |
| | | | $V_{OD} = 0V$ | | -8 | -11 | |
| $I_{O(OFF)}$ | Power-off output current | | $V_{CC} = 0V, V_O = 3.6V$ | | | ± 1 | μA |
| C_{IN} | Input capacitance | | | 7 | | | pF |

Receiver Electrical Characteristics (Over recommended operating conditions unless otherwise noted).

| Parameter | | Test Conditions | Min. | Typ. | Max. | Units |
|--------------|---|-------------------------|------|------|----------|---------|
| V_{ITH+} | Positive-going differential input voltage threshold | See Figures 4 & Table 1 | | | 50 | mV |
| V_{ITH-} | Negative-going differential input voltage threshold | | -50 | | | |
| V_{OH} | High-level output voltage | $I_{OH} = -8mA$ | 2.4 | | | V |
| V_{OL} | Low-level output voltage | $I_{OL} = 8mA$ | | | 0.4 | V |
| I_I | Input current (R_{IN+} or R_{IN-}) | $V_I = 0$ | -2 | -11 | -20 | μA |
| | | $V_I = 2.4V$ | -1.2 | -3 | | |
| $I_{I(OFF)}$ | Power-off input current (R_{IN+} or R_{IN-}) | $V_{CC} = 0$ | | | ± 20 | |
| I_{IH} | High-level input current (enables) | $V_{IH} = 2V$ | | | ± 10 | |
| I_L | Low-level input current (enables) | $V_{IL} = 0.8V$ | | | ± 10 | |
| C_I | Input capacitance | | | 5 | | pF |

Note: All typical values are at 25°C with a 3.3V supply

Driver Switching Characteristics (Over recommended operating conditions unless otherwise noted).

| Parameter | | Test Conditions | Min. | Typ. ⁽¹⁾ | Max. | Units |
|--------------|--|---|------|---------------------|------|-------|
| t_{PLH} | Propagation delay time, low-to-high-level output | $R_L = 100$ ohms $C_L = 10$ pF See Figure 2 | | 1.9 | 2.5 | ns |
| t_{PHL} | Propagation delay time, high-to-low-level output | | | 1.9 | 2.5 | |
| t_r | Differential output signal rise time | | | 0.6 | 1.1 | |
| t_f | Differential output signal fall time | | | 0.6 | 1.1 | |
| $t_{sk(p)}$ | Pulse skew ($t_{PHL} - t_{PLH}$) | | | 270 | | ps |
| $t_{sk(pp)}$ | Part-part-part skew ⁽²⁾ | | | | 0.9 | ns |

Notes:

1. All typical values are at 25°C with a 3.3V supply.
2. $t_{sk(pp)}$: magnitude of difference in propagation delay times between any specific terminals of two devices (all things being equal).

Receiver Switching Characteristics (Over recommended operating conditions unless otherwise noted).

| Parameter | | Test Conditions | Min. | Typ. ⁽¹⁾ | Max. | Units |
|-----------------------------|--|-------------------------------|------|---------------------|------|-------|
| t_{PLH} | Propagation delay time, low-to-high-level output | $C_L = 10$ pF See Figure 5 | | 2.0 | 3.1 | ns |
| t_{PHL} | Propagation delay time, high-to-low-level output | | | 2.2 | 3.1 | |
| $t_{sk(pp)}$ ⁽²⁾ | Part-part-part skew ⁽²⁾ | | | | 1.3 | |
| $t_{sk(p)}$ | Pulse skew ($t_{PHL} - t_{PLH}$) | | | 300 | 500 | ps |
| t_r | Output signal rise time | | | 0.9 | 1.5 | ns |
| t_f | Output signal fall time | | | 1.0 | 1.8 | ns |

Notes:

1. All typical values are at 25°C with a 3.3V supply
2. $t_{sk(pp)}$: magnitude of difference in propagation delay times between any specific terminals of two devices (all things being equal)

Parameter Measurement Information

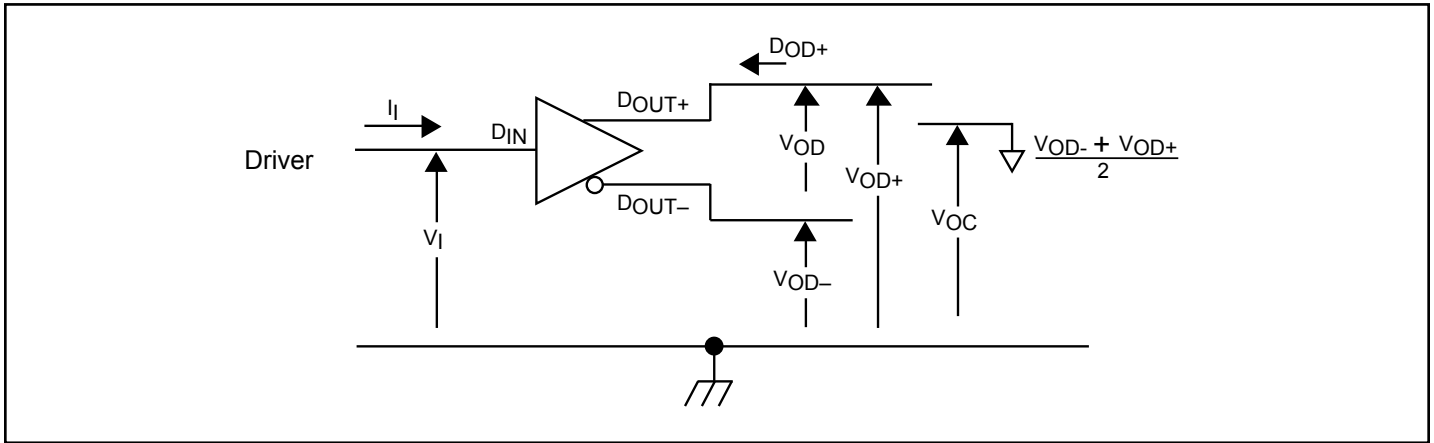


Figure 1. Driver Voltage and Current Definitions

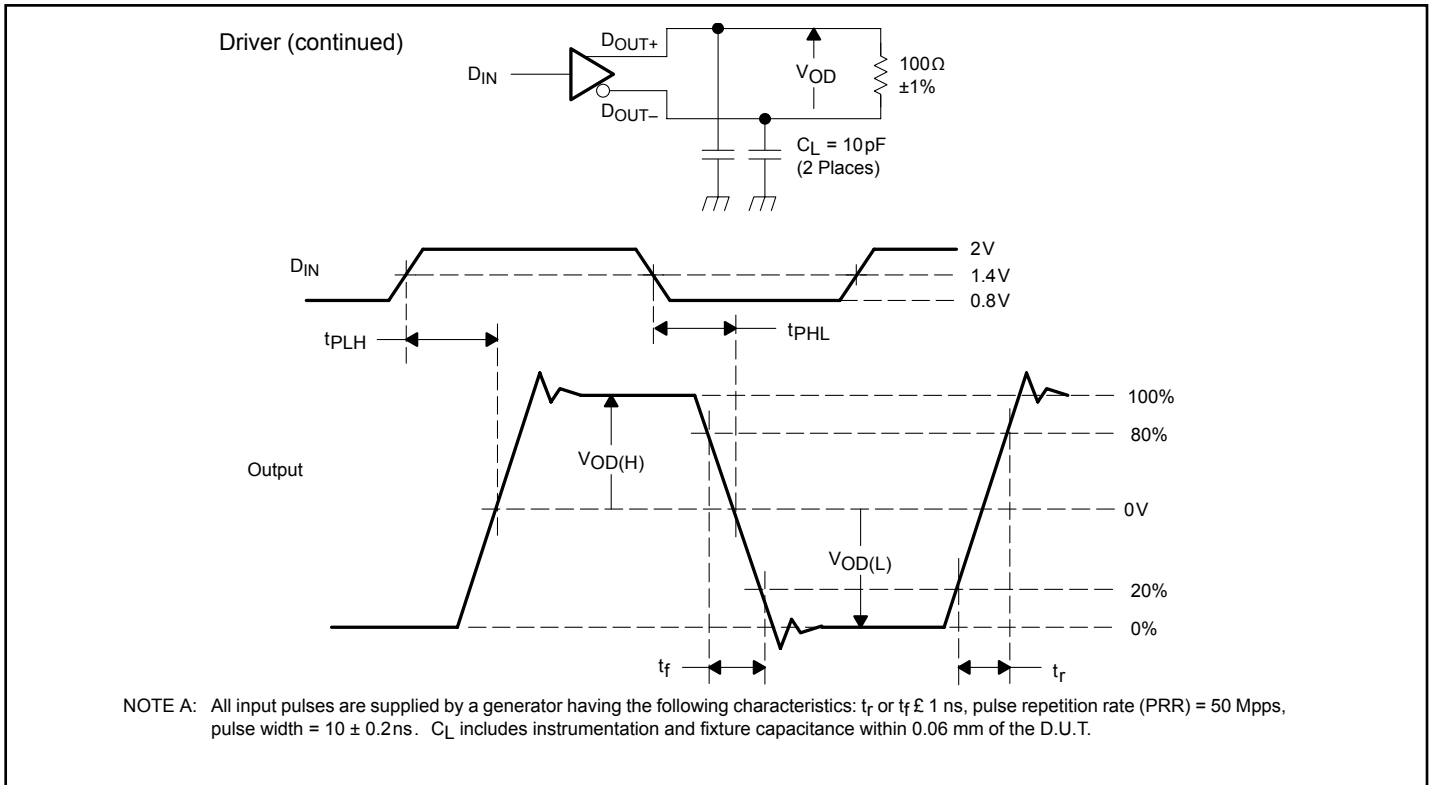


Figure 2. Test Circuit, Timing, and Voltage Definitions for the Differential Output Signal

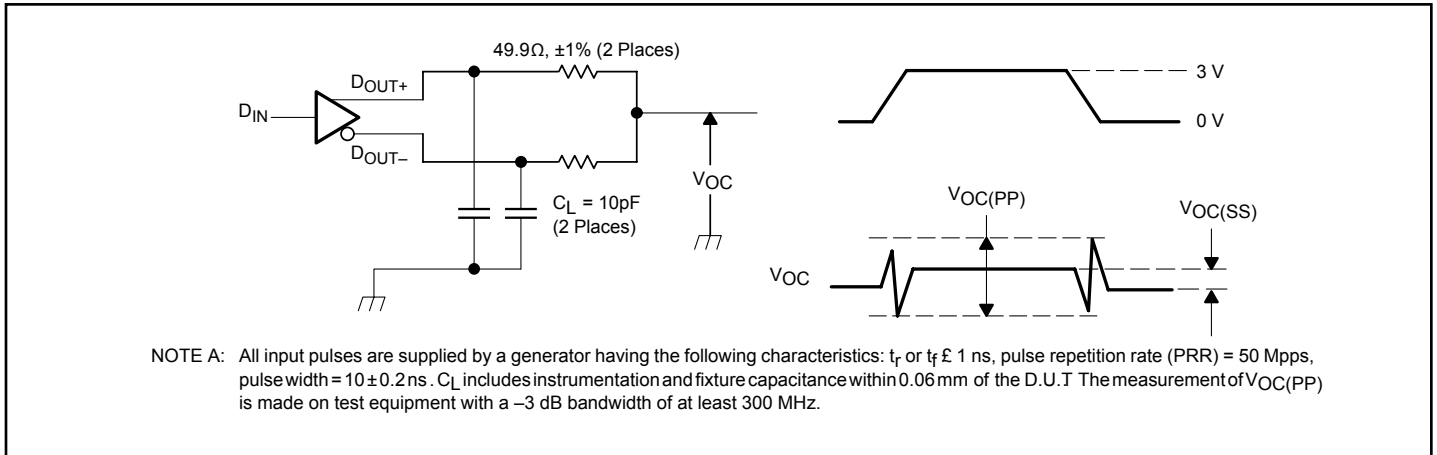


Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

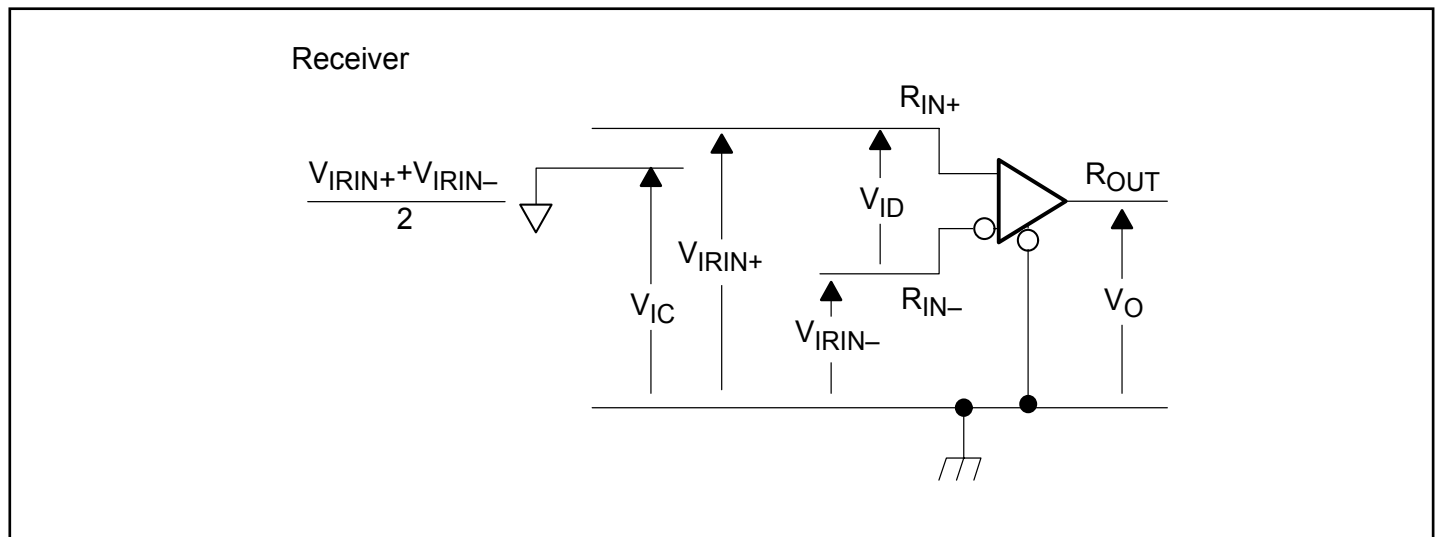


Figure 4. Receiver Voltage Definitions

Table 1. Receiver Minimum and Maximum Input Threshold Test Voltages

| APPLIED VOLTAGES (V) | | RESULTING DIFFERENTIAL INPUT VOLTAGE (mV) | RESULTING COMMON-MODE INPUT VOLTAGE (V) |
|----------------------|-------------|---|---|
| V_{IRIN+} | V_{IRIN+} | V_{ID} | V_{IC} |
| 1.225 | 1.175 | 50 | 1.2 |
| 1.175 | 1.225 | -50 | 1.2 |
| 2.375 | 2.325 | 50 | 2.35 |
| 2.325 | 2.375 | -50 | 2.35 |
| 0.1 | 0 | 50 | 0.05 |
| 0 | 0.05 | -50 | 0.05 |
| 1.5 | 0.9 | 600 | 1.2 |
| 0.9 | 1.5 | -600 | 1.2 |
| 2.4 | 1.8 | 600 | 2.1 |
| 1.8 | 2.4 | -600 | 2.1 |
| 0.6 | 0 | 600 | 0.3 |
| 0 | 0.6 | -600 | 0.3 |

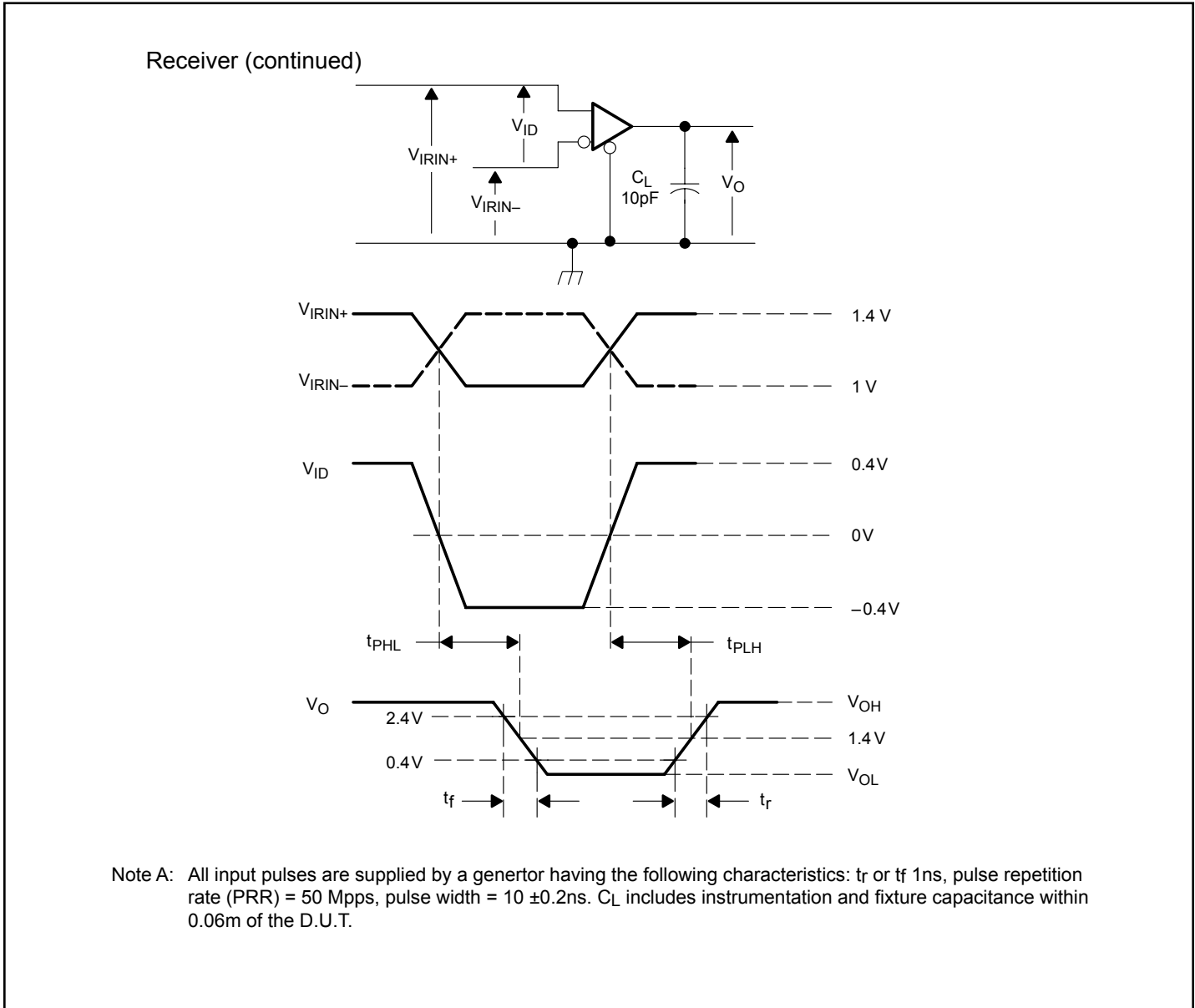


Figure 5. Timing Test Circuit and Waveforms

Packaging Mechanical: 8-Pin SOIC (W)

| SYMBOLS | MIN. | NOM. | MAX. |
|----------------|----------|------|------|
| A | — | — | 1.75 |
| A1 | 0.10 | — | 0.25 |
| A2 | 1.25 | — | — |
| b | 0.31 | — | 0.51 |
| c | 0.10 | — | 0.25 |
| D | 4.80 | 4.90 | 5.00 |
| E | 5.80 | 6.00 | 6.20 |
| E1 | 3.80 | 3.90 | 4.00 |
| e | 1.27 BSC | | |
| L | 0.40 | — | 1.27 |
| h | 0.25 | — | 0.50 |
| θ° | 0 | — | 8 |

UNIT : mm

NOTE :
 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES
 2. DIMENSIONS EXCLUDE BURRS, MOLD FLASH OR PROTRUSIONS
 3. REFER JEDEC MS-012

| | | |
|--|-------------|----------------|
| PERICOM Enabling Serial Connectivity | | DATE: 02/21/14 |
| DESCRIPTION: 8-Pin, 150mil-Wide, SOIC | | |
| PACKAGE CODE: W (W8) | | |
| DOCUMENT CONTROL #: PD-1001 | REVISION: G | |

15-0103

Packaging Mechanical: 8-Pin MSOP (U)

| PKG. DIMENSIONS(MM) | | |
|---------------------|----------|------|
| SYMBOL | Min. | Max. |
| A | — | 1.10 |
| A1 | 0.00 | 0.15 |
| A2 | 0.75 | 0.95 |
| b | 0.22 | 0.38 |
| c | 0.08 | 0.23 |
| D | 2.90 | 3.10 |
| E | 2.90 | 3.10 |
| E1 | 4.65 | 5.15 |
| e | 0.65 BSC | |
| L | 0.40 | 0.80 |
| θ | 0° | 8° |

| | | |
|---|--|----------------|
| <p>NOTE: 1. ALL DIMENSIONS ARE IN MILLIMETERS. 2. REFER JEDEC MO-187E/AA 3. PACKAGE OUTLINE DIMENSIONS DO NOT INCLUDE MOLD FLASH AND METAL BURR.</p> | | DATE: 10/20/14 |
| | DESCRIPTION: 8-Pin, Mini Small Outline Package, MSOP | |
| | PACKAGE CODE: U (U8) | |
| | DOCUMENT CONTROL #: PD-1261 | REVISION: E |

Note: For latest package info, please check: <http://www.pericom.com/support/packaging/packaging-mechanicals-and-thermal-characteristics/>

Ordering Information

| Ordering Number | Package Code | Package Description |
|-----------------|--------------|---|
| PI90LV179WE | W | 8-Pin, 150mil-Wide (SOIC) |
| PI90LV179WEX | W | 8-Pin, 150mil-Wide (SOIC), Tape & Reel |
| PI90LV179UE | U | 8-Pin, Mini Small Outline Package (MSOP) |
| PI90LV179UEX | U | 8-Pin, Mini Small Outline Package (MSOP), Tape & Reel |

Notes:

- Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- E = Pb-free and Green
- X suffix = Tape/Reel